

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- · Low threshold voltage
- Trench MOSFET technology
- Side wettable flanks for optical solder inspection
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Exposed drain pad for excellent thermal conduction

3. Applications

- Charging switch for portable devices
- DC-to-DC converters
- Power management in battery-driven portable devices
- Hard disk and computing power management

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-12	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-12.7	А
Static characte	eristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -8.6 A; T _j = 25 °C		-	14	19	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		
4	S	source		S
5	D	drain	Transparent top view	017aaa094
6	D	drain	DFN2020MD-6 (SOT1220)	
7	D	drain		
8	S	source		

6. Ordering information

Table 3. Ordering information

Type number	Package	ige					
	Name	Description	Version				
PMPB14XP	DFN2020MD-6	DFN2020MD-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMPB14XP	5B

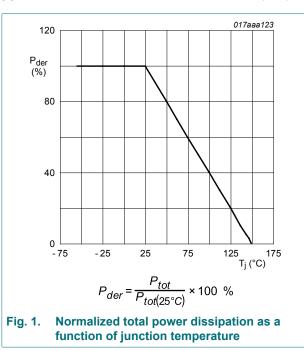
8. Limiting values

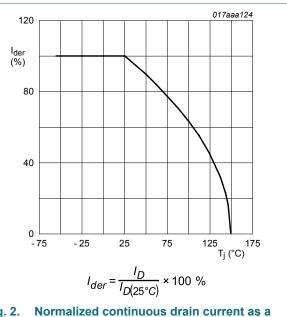
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-12	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-12.7	А
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-8.6	А
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-5.4	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-35	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1]	-	1.8	W
		T _{amb} = 25 °C; t ≤ 5 s	[1]	-	3.9	W
		T _{sp} = 25 °C		-	15.6	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode			·		
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.6	А

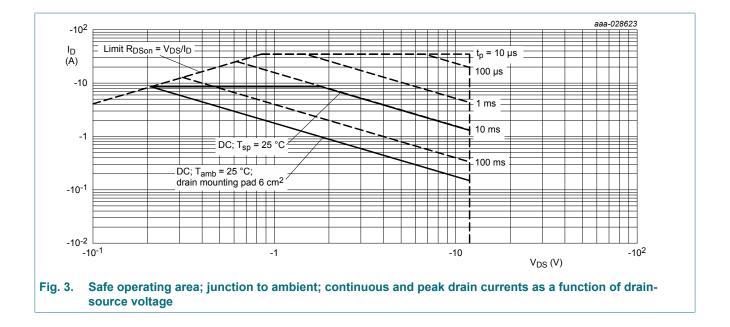
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².







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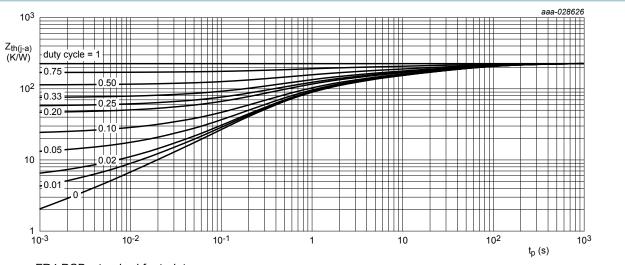
9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-a)}	thermal resistance		[1]	-	226	260	K/W
	from junction to ambient		[2]	-	60	70	K/W
		in free air; t ≤ 5 s	[2]	-	27	32	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	4	8	K/W

Table 6 Thermal characteristics

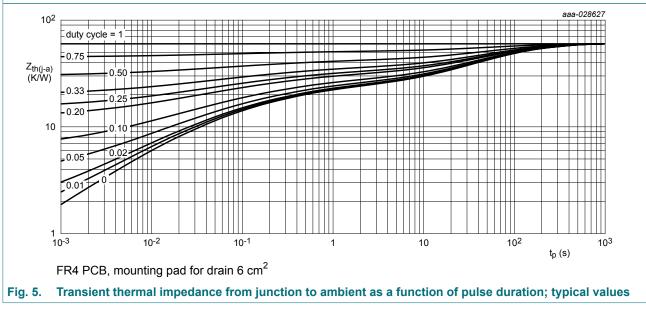
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



FR4 PCB, standard footprint

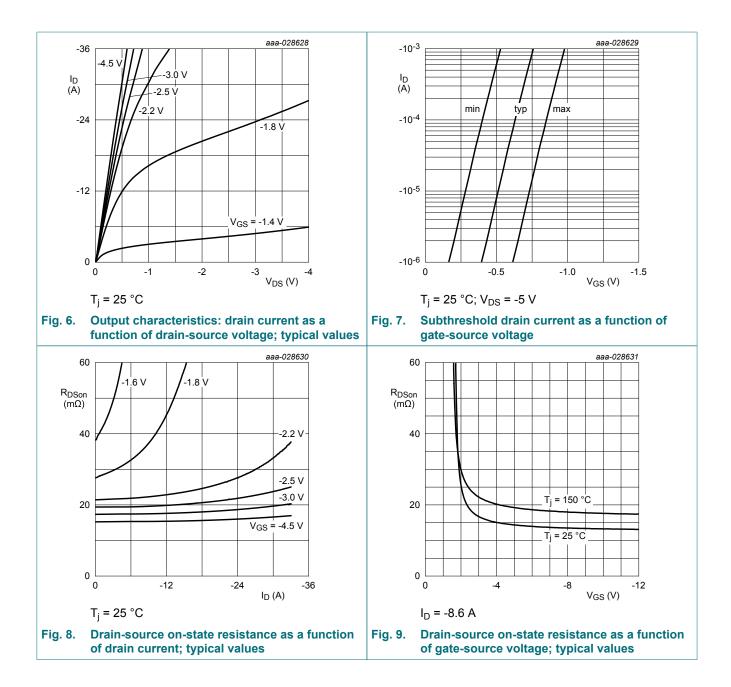




10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
- Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-12	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.45	-0.68	-0.9	V
I _{DSS}	drain leakage current	V _{DS} = -12 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V _{GS} = -4.5 V; I _D = -8.6 A; T _j = 25 °C	-	14	19	mΩ
	resistance	V _{GS} = -4.5 V; I _D = -8.6 A; T _j = 150 °C	-	18	24	mΩ
		V_{GS} = -2.5 V; I _D = -3.9 A; T _j = 25 °C	-	19	25	mΩ
		V _{GS} = -1.8 V; I _D = -1 A; T _j = 25 °C	-	24	42	mΩ
9 _{fs}	forward transconductance	V _{DS} = -10 V; I _D = -8.6 A; T _j = 25 °C	-	92	-	S
R _G	gate resistance	f = 1 MHz	-	5.4	-	Ω
Dynamic ch	naracteristics			-	1	
Q _{G(tot)}	total gate charge	V_{DS} = -6 V; I _D = -8.6 A; V _{GS} = -4.5 V;	-	22	42	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	3.8	-	nC
Q _{GD}	gate-drain charge		-	5.8	-	nC
C _{iss}	input capacitance	V _{DS} = -6 V; f = 1 MHz; V _{GS} = 0 V;	-	2303	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	482	-	pF
C _{rss}	reverse transfer capacitance		-	417	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -6 V; I _D = -8.6 A; V _{GS} = -4.5 V;	-	4	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	9	-	ns
t _{d(off)}	turn-off delay time		-	64	-	ns
t _f	fall time		-	36	-	ns
Source-drai	in diode	· · · ·				
V _{SD}	source-drain voltage	I _S = -1.6 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.7	-1.2	V

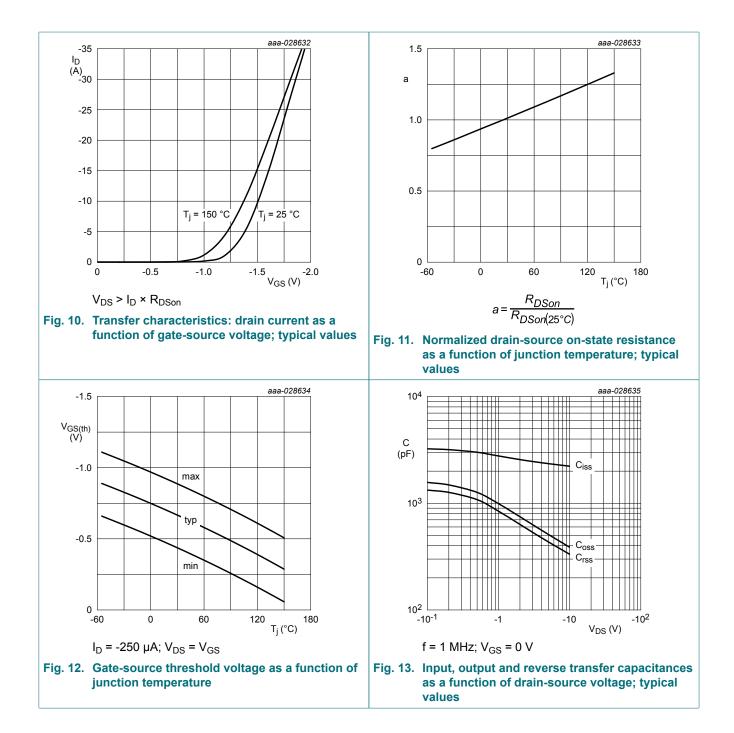
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PMPB14XP

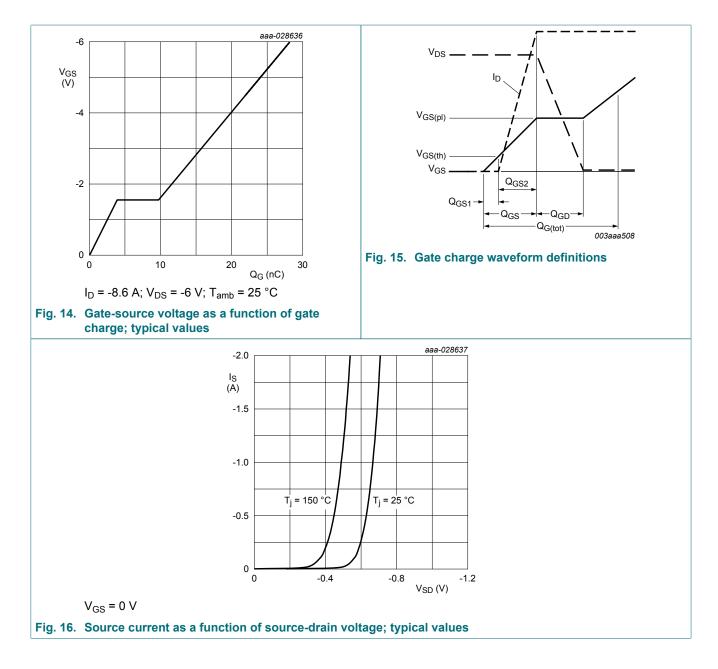
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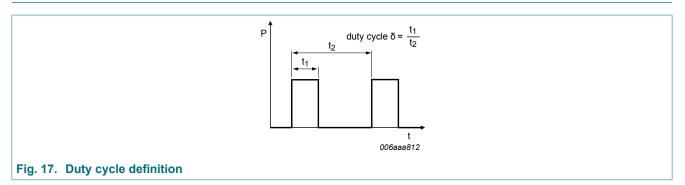
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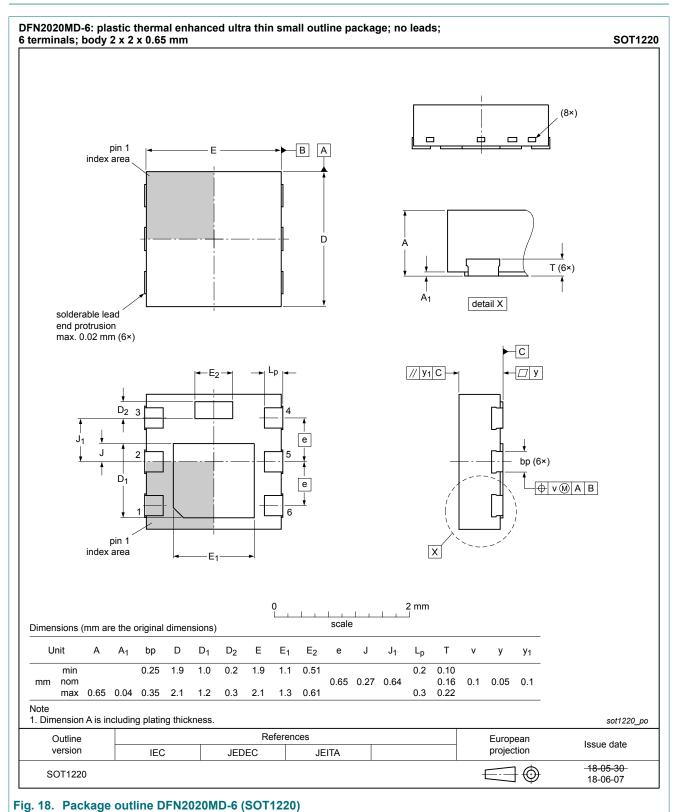
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11. Test information



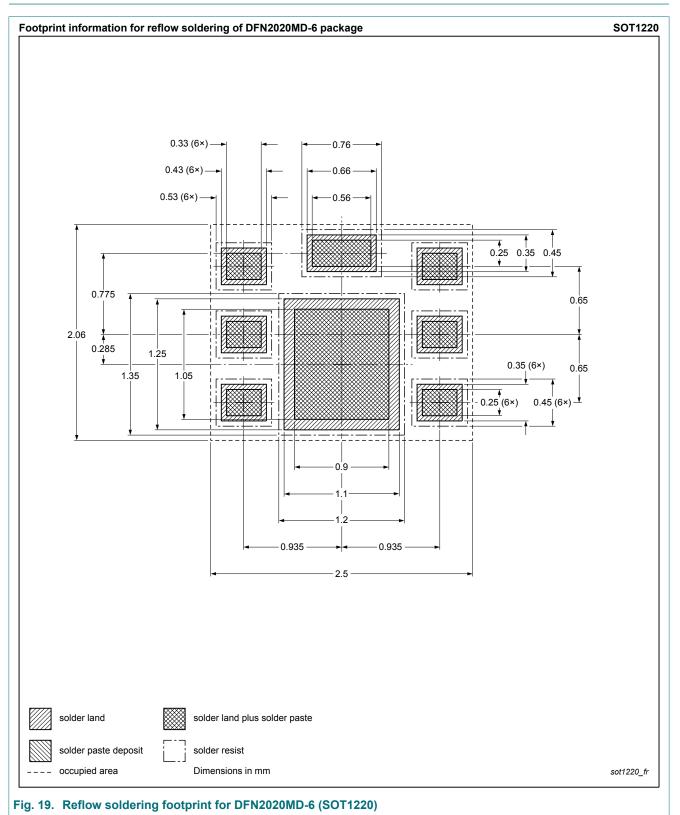
12. Package outline



PMPB14XP

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13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMPB14XP v.1	20180703	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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